## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Leo Mathew et al.

Group Art Unit:

Application No.:

Unassigned

Examiner:

Unassigned

Date Filed: Title:

Concurrent Herewith

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ELECTRODES AND METHOD OF FORMATION

## INFORMATION DISCLOSURE STATEMENT (IDS)

Commissioner For Patents Alexandria, VA 22313

### SIR:

In accordance with 37 C.F.R. §1.56 and in compliance with 37 C.F.R. §§1.97 and 1.98, the references listed on attached Form PTO/SB/08 and/or subsequently identified herein, are for consideration by the United States Patent and Trademark Office. Pursuant to the Office waiving the requirement under 37 CFR 1.98 (a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. patent application publication for all U.S. national patent applications filed after June 30, 2003 and for all international applications that have entered the national stage under 35 USC §371 after June 30, 2003, copies of the reference are not submitted herewith.

#### I. COPIES

- a. 🔯 A legible copy of (i) each foreign patent; (ii) each publication or that portion which caused it to be listed; and (iii) all other information or that portion which caused it to be listed, is included herewith.
- Any patents, publications or other information which are listed on PTO/SB/08 which are not Ь.□ enclosed herewith were previously cited by or submitted to the PTO in one of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. §120:

U.S. Serial Number

U.S. Filing Date

#### CONCISE EXPLANATION OF THE RELEVANCE (check at least one box) П.

- Except as may be indicated below in (b) of this section, all of the patents, publications or other a. 🔯 information are in the English language (concise explanation not required).
- A concise explanation of the relevance of all patents, publications or other information listed ь. П that is not in the English language is as follows:
- c. 🔲 The following additional information is provided for the Examiner's consideration:

#### III. 🛛 CROSS REFERENCE TO RELATED APPLICATION(S)

The Examiner is advised that the following co-pending application(s) contain(s) subject matter that may be related to the present application. By bringing this (these) applications to the Examiner's attention, Applicant(s) does(do) not waive the confidentiality provisions of 35 U.S.C. §122.

Serial No.	Filing Date	Art Unit
10/074,732	09-03-2002	2815
10/427,141	04-30-2003	2811
10/443,375	05-22-2003	. 1765
10/443,908	05-22-2003	2818

# **FEES**

IV. 🔀		within three months of the filing date of a national application other than a continued
		prosecution application under § 1.53(d) (37 C.F.R. §1.97(b)(1)). No fee or statement is required.
	b. 🗌	within three months of the date of entry of the national stage as set forth in § 1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement is required.
	c.🛛	before the mailing date of a first Office Action on the merits (37 C.F.R. §1.97(b)(3)). No fee or statement is required.
	d.	before the mailing date of a first Office Action after the filing of a request for continued examination under § 1.114 (37 C.F.R. § 1.97(b)(4)). No fee or statement is required.
V. 🗀	before the	OS IS BEING FILED UNDER 37 C.F.R. §1.97(c): (check one box) the mailing date of any of a Final Office Action under 37 C.F.R. §1.113, a Notice of Allowance 7 C.F.R. §1.311, or an action that otherwise closes prosecution in the application (See 37 C.F.R. §1.31).
	a.     b.	No statement; therefore, charge deposit account <b>502117</b> the fee set forth in 37 C.F.R. §1.17(p). See the statement below. No fee is required.
VI. 🔲		OS IS BEING FILED UNDER 37 C.F.R. §1.97(d):
	on or be	fore payment of the issue fee and is accompanied by the following: a statement under 37 C.F.R. §1.97(e) as provided below; and
	2)	charge deposit account 502117 the petition fee set forth in §1.17(p).
VII.		MENT UNDER 37 C.F.R. §1.97(e) (check only one box, if applicable) ersigned hereby states that
	a	each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of IDS; or
	b. 🗌	no item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application, and to knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement, or
	c.	some of the items of information contained in the IDS were cited in a communication from a foreign Patent Office. As to this information, the undersigned states that each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of this IDS. As to the remaining information, the undersigned hereby states that no item of this remaining information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application or, to the knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement.

VIII.	PAYM	ENT OF I	FEES	
			in the amount of is enclosed for the above-identified fee(s).	
			harge Deposit Account 502117 in the amount of \$180.00 for the above-indicated	
	$\boxtimes$	fee(s).	cont has availabled any additional face or if any available has been used the	
			cant has overlooked any additional fees, or if any overpayment has been made, the ssioner is hereby authorized to credit or debit Deposit Account 502117.	
			pies of this paper are attached for Deposit Account charges and debits.	
	te statuto	ory prior	nces are being cited only in the interests of candor and without any admission that the art or contain matter which anticipates the invention or which would render the same a combination, to a person of ordinary skill in the art.	
	determine he prope	ed that thi	has any questions concerning this IDS, he/she is requested to contact the undersigned is IDS has been filed under the wrong rule, the PTO is requested to consider this ID ith a petition if necessary) and charge the appropriate fee to Deposit Account No.	S
			Respectfully submitted,	
			Leo Mathew et al.	
			P1+4 /	
			Robert L. King	
мото	ROLA, I	NC	Attorney for Applicant(s)	
		er 23125	Reg. No. 30,185	
			Tel. 512-996-6839	
Enclosu	ires:	$\boxtimes$	PTO/SB/08	
		$\bowtie$	References A-19 thru A-34	
		H	Foreign Search Report Other:	
		LJ .	Offici.	

PTO/SB/08A (04-03)

Substitute for form 1449A/PTO				Complete if Known				
				Application Number				
INFORMATION DISCLOSURE				Filing Date				
	STATEMENT BY APPLICANT			First Named Inventor	Leo Mathew et al.			
	SIAIEMENIE	OT APPLICA	4141	Group Art Unit	Unassigned			
(use as many sheets as necessary)				Examiner Name	Unassigned			
Sheet	1	of	3	Attorney Docket Number	SC12733TP			

Examiner Initials*	Cite No. 1	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevan Passages or Relevant Figures Appear
unuais		Number -Kind Code <sup>2</sup> (if known)	WIWI-DD-1111	Or Orica Bosameni	1 assages of Holerann I iguide i ppeur
	A-1	US - 6,583,469	06-24-2003	Fried et al.	
	A-2	US - 2003/113970 A1	06-19-2003	Fried et al.	
	A-3	US - 6,472,258	10-29-2002	Adkisson et al.	
	A-4	US - 6,458,662	10-01-2002	Yu	
	A-5	US - 6,433,609	08-13-2002	Voldman	
	A-6	US - 6,414,356	07-02-2002	Forbes et al.	
	A-7	US - 6,413,802	07-02-2002	Hu et al.	
	A-8	US - 6,396,108	05-28-2002	Krivokapic et al.	
	A-9	US - 6,372,559	04-16-2002	Crowder et al.	
	A-10	US - 6,355,961	03-12-2002	Forbes	
	A-11	US - 6,330,184	12-11-2001	White et al.	
	A12	US - 6,300,182	10-09-2001	Yu	
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	A-15	US - 6,011,725	01-04-2000	Eitan	
	A-16	US - 5,804,848	09-08-1998	Mukai	
	A-17	US - 5,689,127	11-18-1997	Chu et al.	
	A-18	US -4,859,623	08-22-1989	Busta	

			PATENT DOCUMENT		T	
Examine Cite No. 1	Foreign Patent Document	Publication Date	Name of Patentee or	Pages, Columns, Lines,	T 6	
r		Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>2</sup> (if	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages or	
Initials*	ļ	known)			Relevant Figures Appear	
	A-19	DE 101 25 967 C1	05-29-2001	Schlösser et al.		
	A-20	WO 00/21118	04-13-2000	Marso et al.		
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Examiner	Date .
Signature	Considered
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> See Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English Language Translation is attached.

If you need assistance in completing the form, call 1-800-PTO-9199 (1-800-786-9199) and select option 2.

Substitute fo	or form 1449A/PTO				Complete if Known	
				Application Number		
	INFORMATION	DISCLOSU	JRE	Filing Date		
	STATEMENT B	Y APPLICA	NT	First Named Inventor	Leo Mathew et al.	
	OIAIEMENI E	, All LIO		Group Art Unit	Unassigned	
(use as many sheets as necessary)				Examiner Name	Unassigned	
Sheet	2	of	3	Attorney Docket Number	SC12733TP	

Examiner	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal,	T
Initials*		serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	•
	A-21	Related Application 10/074,732 entitled "Method of Forming a Vertical Double Gate Semiconductor Device and Structure Thereof" filed September 3, 2002 entitled	
	A-22	Related Application 10/443,375 entitled "Transistor With Independent Gate Structures" filed May 22, 2003	
	A-23	Related Application 10/443,908 "Memory with Charge Storage Locations" entitled filed May 22, 2003	
	A-24	Related Application 10/427,141 entitled "Semiconductor Fabrication Process with Asymmetrical Conductive Spacers" filed April 30, 2003	
	A-25	LEE et al.; "Multilevel Vertical-Channel SONOS Nonvolatile Memory on SOI"; IEEE Electron Device Letters, 2002; pp 1-3 and 208-209.	
	A-26	YU, BIN et al; "FinFET Scaling to 10nm Gate Length:; IEEE IDEM 2002; pp 251-254; IEEE	
	A-27	CHOI, YANG-KYU et al.; "Sub-20nm CMOS FinFET Technologies"; 2001 IEEE, 4 pp	
	A-28	KEDZIERSKI, JAKUB et al.; "High-Performance Symmetric-Gate and CMOS-Compatible Vt Asymmetric-Gate FinFET Devi ces"; 2001; IEEE; 4 pp.	
	A-29	KIM, KEUNWOO et al.; "Double-Gate CMOS Symmetrical – Versus Asymmetrical-Gate Devices"; IEEE Transactions On Electron Devices, Vol 48, No. 2; February 2001; pp 294-299.	
	A-30	FOSSUM, JERRY G. et al.; "Extraordinarily High Drive currents in Asymmetrical Double-Gate MOSFETS"; Superlattices and Microstructures, Vol 28, No. 5/6, 2000, 2000 Academic Press, pp 525-530.	
xaminer	L,	Date	L

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.

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Substitute	for form 1449	A/PTO			Compl	lete if Known
					Application Number	
	INFORI	MATION DISC	LOSUF	RE	Filing Date	
	STATEMENT BY APPLICANT				First Named Inventor	Leo Mathew et al.
					Group Art Unit	Unassigned
(use as ma	any sheets as i	necessary)			Examiner Name	Unassigned
Sheet 3 of 3				3	Attorney Docket Number	SC12733TP
					A Self-Aligned Double-Gate MC 12, December 2000, pp 2320-232	OSFET Scalable to 20 nm"; IEEE Transactions 5.
	A-32				Operation of V <sub>th</sub> -Adjusted <sup>p+n+</sup> Doul 994; pgs 386-388.	ole Gate SOI MOSFET's; IEEE Electron Devic
	A-33	•		e Single-Trans 95; Vol. EDL-8		M Device"; IEEE Electron Device Letters;
						nsion (DSDE) MOSFET Using a Separately

Examiner	Date	
Signature	Considered	

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